

MC78MXX/LM78MXX

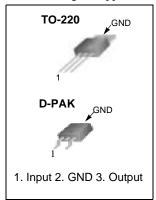
3-Terminal 0.5A Positive Voltage Regulator

Features

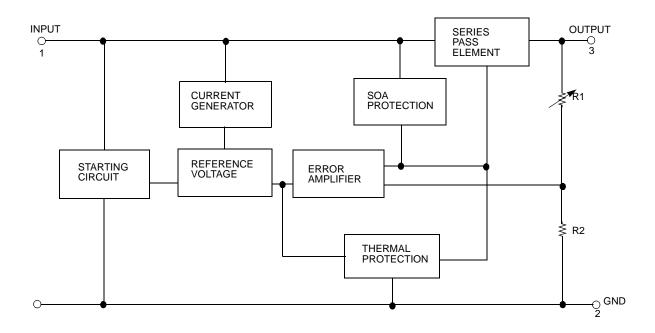
- Output Current up to 0.5A
- Output Voltages of 5, 6, 8, 12, 15, 18, 24V
- Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe Operating Area (SOA)Protection

Description

The MC78MXX/LM78MXX series of three-terminal positive regulators are available in the TO-220/D-PAK package with several fixed output voltages making it useful in a wide range of applications.



Internal Block Digram



Rev. 1.0.5

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for V _O = 5V to 18V) (for V _O = 24V)	V _I V _I	35 40	V V
Thermal Resistance Junction-Case (Note1) TO-220 (Tc = +25°C)	ReJC	2.5	°C/W
Thermal Resistance Junction-Air (Note1, 2) TO-220 (Ta = +25°C) D-PAK (Ta = +25°C)	ReJA	66 92	°C/W
Operating Junction Temperature Range	TOPR	0 ~ +150	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

Note:

- Thermal resistance test board Size: 76.2mm * 114.3mm * 1.6mm(1S0P) JEDEC standard: JESD51-3, JESD51-7
- 2. Assume no ambient airflow

Electrical Characteristics (MC78M05/LM78M05)

(Refer to the test circuits, $0 \le TJ \le +125$ °C, IO=350mA, VI=10V, unless otherwise specified, CI = $0.33\mu F$, CO= $0.1\mu F$)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J = +25°C		4.8	5	5.2	
Output Voltage	Vo	IO = 5mA to 35 V _I = 7V to 20V	0mA	4.75	5	5.25	V
Line Regulation (Note3)	ΔVο	IO = 200mA	V _I = 7V to 25V	-	-	100	mV
Line Regulation (Notes)	ΔνΟ	TJ =+25°C	V _I = 8V to 25V	-	-	50	IIIV
Load Regulation (Note3)	ΔVο	IO = 5mA to 0.5	5A, TJ =+25°C	-	-	100	mV
Load (Negulation (Notes)	ΔνΟ	I _O = 5mA to 20	0mA, T _J =+25 °C	-	-	50	IIIV
Quiescent Current	IQ	TJ =+25°C		-	4.0	6.0	mA
		I _O = 5mA to 35	0mA	-	-	0.5	
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 8V to 25V		-	-	0.8	mA
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +125°C		-	-0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100	kHz	-	40	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 300mA VI = 8V to 18V, T _J =+25 °C		-	80	-	dB
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V
Short Circuit Current	Isc	TJ =+25°C, VI = 35V		-	300	-	mA
Peak Current	IPK	T _J =+25°C		-	700	-	mA

^{3.} Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M06) (Continued)

(Refer to the test circuits, $0 \le TJ \le +125$ °C, IO=350mA, VI =11V, unless otherwise specified, CI=0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J = +25°C		5.75	6	6.25	
Output Voltage	Vo	IO = 5mA to 3 V _I = 8V to 21		5.7	6	6.3	V
Line Regulation (Note1)	ΔVο	Io = 200mA	VI = 8V to 25V	-	-	100	mV
Line Regulation (Note 1)	ΔνΟ	T _J = +25°C	V _I = 9V to 25V	-	-	50	1111
Load Regulation (Note1)	ΔVο	IO = 5mA to 0).5A, T _J = +25°C	-	-	120	mV
Load Regulation (Note1)	ΔνΟ	IO = 5mA to 2	200mA, T _J = +25°C	-	-	60	1111
Quiescent Current	IQ	TJ = +25°C		-	4.0	6.0	mA
		I _O = 5mA to 350mA		-	-	0.5	
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 9V to 25V		-	-	0.8	mA
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +12	5°C	-	-0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 10	00kHz	-	45	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 300mA VI = 9V to 19V, T _J =+25 °C		-	80	-	dB
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = 35V		-	300	-	mA
Peak Current	IPK	TJ =+25°C		-	700	-	mA

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M08) (Continued)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, $I_O=350mA$, $V_I=14V$, unless otherwise specified, $C_I=0.33\mu F$, $C_O=0.1\mu F$)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit		
		T _J =+25°C		T _J =+25°C		7.7	8	8.3	
Output Voltage	Vo	IO = 5mA to 350 V _I = 10.5V to 23	-	7.6	8	8.4	V		
Line Regulation (Note1)	ΔVο	IO = 200mA	V _I = 10.5V to 25V	-	-	100	mV		
Line Regulation (Note 1)	ΔνΟ	TJ =+25°C	V _I = 11V to 25V	-	-	50	IIIV		
Load Population (Note1)	ΔVο	IO = 5mA to 0.5	5A, TJ =+25°C	-	-	160	mV		
Load Regulation (Note1)	ΔνΟ	I _O = 5mA to 200	0mA, TJ =+25°C	-	-	80	1117		
Quiescent Current	IQ	TJ = +25°C		-	4.0	6.0	mA		
		I _O = 5mA to 350mA I _O = 200mA V _I = 10.5V to 25V		-	-	0.5			
Quiescent Current Change	ΔlQ			-	-	0.8	mA		
Output Voltage Drift	RR	IO = 5mA T _J = 0 to +125°C		-	-0.5	-	mV/°C		
Output Noise Voltage	VN	f = 10Hz to 100	kHz	-	52	-	μV/Vo		
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 11.5V to 21.5V, T _J =+25 °C		-	80	-	dB		
Dropout Voltage	VD	T _J = +25°C, I _O = 500mA		-	2	-	V		
Short Circuit Current	Isc	T _J = +25°C, V _I = 35V		-	300	-	mA		
Peak Current	IPK	T _J = +25°C		-	700	-	mA		

^{1.} Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M12) (Continued)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, IO=350mA, VI=19V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit					
			T _J = +25°C		T _J = +25°C		T _J = +25°C		11.5	12	12.5	
Output Voltage	Vo	IO = 5mA to 35 V _I = 14.5V to 2		11.4	12	12.6	V					
Line Regulation (Note1)	4\/0	IO = 200mA	V _I = 14.5V to 30V	-	-	100	mV					
Line Regulation (Note1)	ΔVΟ	T _J = +25°C	V _I = 16V to 30V	-	-	50	IIIV					
Load Regulation (Note1)	ΔVο	IO = 5mA to 0.5	5A, TJ = +25°C	-	-	240	mV					
Load Regulation (Note1)	ΔνΟ	I _O = 5mA to 20	0mA, T _J = +25°C	-	-	120	IIIV					
Quiescent Current	IQ	TJ =+25°C		-	4.1	6.0	mA					
	ΔlQ	I _O = 5mA to 350mA I _O = 200mA V _I = 14.5V to 30V		-	-	0.5						
Quiescent Current Change				-	-	0.8	mA					
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +125°C		-	-0.5	-	mV/°C					
Output Noise Voltage	VN	f = 10Hz to 100	kHz	-	75	-	μV/Vo					
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 15V to 25V, T _J =+25 °C		-	80	-	dB					
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V					
Short Circuit Current	Isc	TJ = +25°C, VI = 35V		-	300	-	mA					
Peak Current	IPK	T _J = +25°C		-	700	-	mA					

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M15) (Continued)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, IO=350mA, VI=23V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit		
		T _J = +25°C	T _J = +25°C		T _J = +25°C		15	15.6	
Output Voltage	Vo	IO = 5mA to 3 V _I = 17.5V to		14.25	15	15.75	V		
Line Regulation (Note1)	ΔVο	IO = 200mA	V _I = 17.5V to 30V	-	•	100	mV		
Line Regulation (Note I)	ΔνΟ	T _J =+25°C	V _I = 20V to 30V	-	-	50	IIIV		
Load Regulation (Note1)	ΔVο	IO = 5mA to 0	0.5A, TJ =+25°C	-	-	300	mV		
Load Negulation (Note I)	ΔνΟ	$I_O = 5mA \text{ to } 2$	200mA, TJ =+25°C	-	-	150	IIIV		
Quiescent Current	IQ	T _J = +25°C		-	4.1	6.0	mA		
		IO = 5mA to 350mA		-	-	0.5			
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 17.5V to	30V	-	-	0.8	mA		
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +12	25°C	-	-1	-	mV/°C		
Output Noise Voltage	VN	f = 10Hz to 1	00kHz	-	100	-	μV/Vo		
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 18.5V to 28.5V, T _J =+25 °C		-	70	-	dB		
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V		
Short Circuit Current	Isc	TJ = +25°C, VI = 35V		-	300	-	mA		
Peak Current	IPK	T _J = +25°C		-	700	-	mA		

^{1.} Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M18) (Continued)

(Refer to the test circuits, $0 \le TJ \le +125$ °C, IO=350mA, VI=26V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit		
		$T_{J} = +25^{\circ}C$		17.3	18	18.7			
Output Voltage	Vo	IO = 5mA to 350 V _I = 20.5V to 33		17.1	18	18.9	V		
Line Regulation (Note1)	ΔVο	Io = 200mA	VI = 21V to 33V	-	-	100	mV		
Line Regulation (Note I)	ΔνΟ	T _J = +25°C	V _I = 24V to 33V	-	-	50	IIIV		
Load Population (Note1)	ΔVΟ	IO = 5mA to 0.5	A, TJ = +25°C	-	-	360	m\/		
Load Regulation (Note1)	ΔνΟ	I _O = 5mA to 200	OmA, T _J = +25°C	-	-	180	mV		
Quiescent Current	lQ	T _J = +25°C		-	4.2	6.0	mA		
		I _O = 5mA to 350mA I _O = 200mA V _I = 21V to 33V		IO = 5mA to 350mA		-	-	0.5	
Quiescent Current Change	ΔlQ			-	-	0.8	mA		
Output Voltage Drift	ΔV/ΔΤ	IO = 5mATJ = 0	to 125°C	-	-1.1	-	mV/°C		
Output Noise Voltage	VN	f = 10Hz to 100	kHz	-	100	-	μV/Vo		
Ripple Rejection	RR	f = 120Hz, IO= 300mA , VI = 22V to 32V TJ =+25 $^{\circ}\text{C}$		-	70	-	dB		
Dropout Voltage	VD	TJ = +25°C, IO = 500mA		-	2	-	V		
Short Circuit Current	Isc	T _J = +25°C, V _I = 35V		-	300	-	mA		
Peak Current	IPK	T _J = +25°C		-	700	-	mA		

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M24) (Continued)

(Refer to the test circuits, $0 \le TJ \le +125$ °C, IO=350mA, VI=33V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J =+25°C		23	24	25	
Output Voltage	Vo	IO = 5mA to V _I = 27V to 3		22.8	24	25.2	V
Line Population (Note1)	۸۱/۵	IO = 200mA	V _I = 27V to 38V	-	-	100	mV
Line Regulation (Note1)	ΔVο	T _J =+25°C	V _I = 28V to 38V	-	-	50	1117
Load Regulation (Note1)	41/0	IO = 5mA to	0.5A, TJ =+25°C	-	-	480	mV
Load Regulation (Note1)	ΔVο	Io = 5mA to	200mA, T _J =+25°C	-	-	240	IIIV
Quiescent Current	IQ	TJ = +25°C		-	4.2	6.0	mA
		I _O = 5mA to 350mA I _O = 200mA V _I = 27V to 38V		-	-	0.5	
Quiescent Current Change	ΔlQ					-	-
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +125°C		-	-1.2	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 1	00kHz	-	170	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 28V to 38V, T _J =+25 °C		-	70	-	dB
Dropout Voltage	VD	T _J = +25°C, I _O = 500mA		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI = 35V		-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	700	-	mA

^{1.} Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Typical Applications

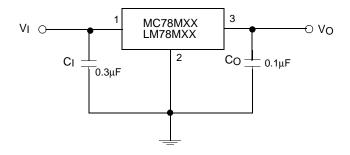


Figure 1. Fixed Output Regulator

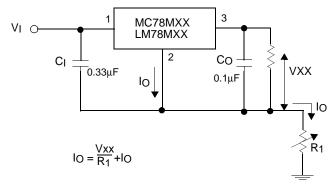


Figure 2. Constant Current Regulator

- 1. To specify an output voltage, substitute voltage value for "XX"
- 2. Although no output capacitor is needed for stability, it does improve transient response.
- 3. C_I is required if regulator is located an appreciable distance from power Supply filter

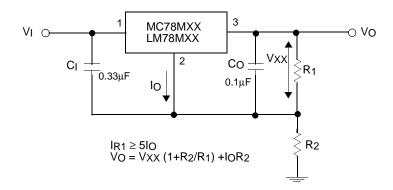


Figure 3. Circuit for Increasing Output Voltage

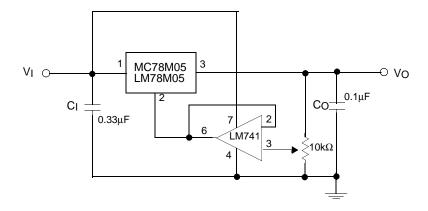


Figure 4. Adjustable Output Regulator (7 to 30V)

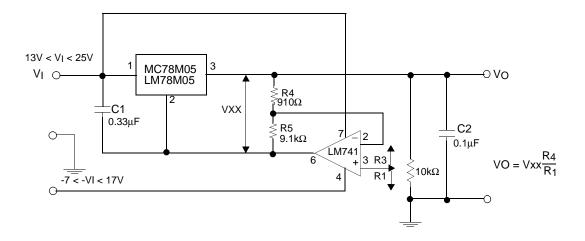


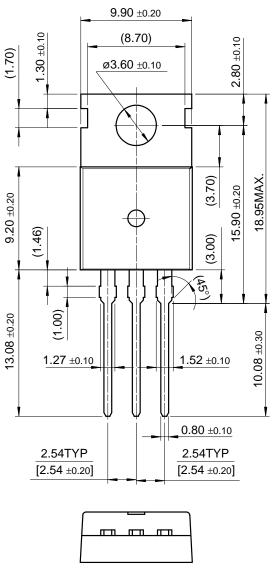
Figure 5. 0.5 to 10V Regulator

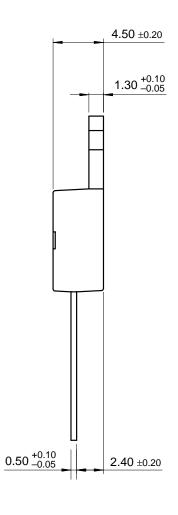
Mechanical Dimensions

Package

Dimensions in millimeters

TO-220

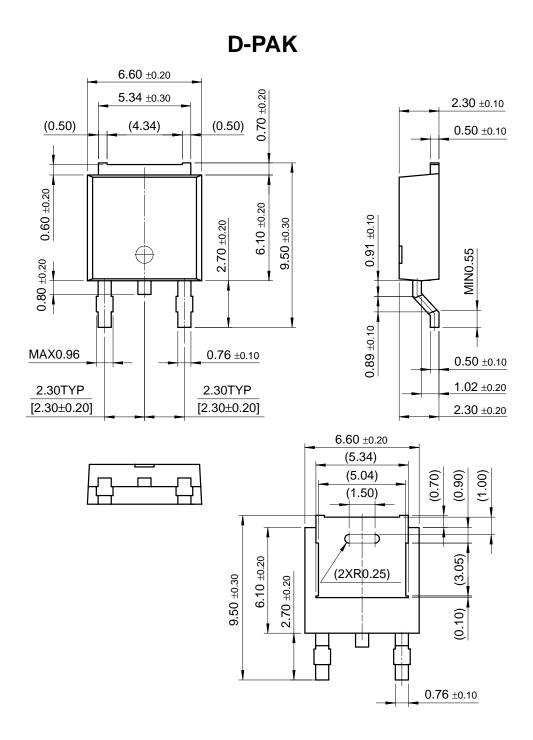




Mechanical Dimensions (Continued)

Package

Dimensions in millimeters



Ordering Information

Product Number	Package	Operating Temperature
LM78M05CT	TO-220	0 ~ +125°C
Product Number	Package	Operating Temperature
MC78M05CT		
MC78M06CT		
MC78M08CT		
MC78M12CT	TO-220	
MC78M15CT		
MC78M18CT		0 ~ +125°C
MC78M24CT		
MC78M05CDT]
MC78M06CDT	D-PAK	
MC78M08CDT	- D-PAK	
MC78M12CDT		

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